Power Transistors

Panasonic

2SB1623A

Silicon PNP epitaxial planar type

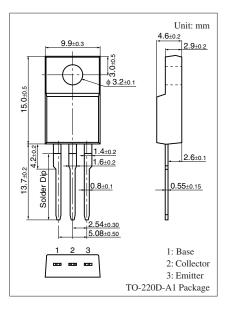
For power amplification

Features

- High forward current transfer ratio h_{FE}
- \bullet Satisfactory linearity of forward current transfer ratio h_{FE}
- Dielectric breakdown voltage of the package: > 5 kV

Absolute Maximum natings $T_a = 25$ C							
Parameter	Symbol	Rating	Unit				
Collector-base voltage (Er	V _{CBO}	-80	V				
Collector-emitter voltage	V _{CEO}	-80	V				
Emitter-base voltage (Col	V _{EBO}	-5	V				
Collector current	I _C	-4	А				
Peak collector current		I _{CP}	-8	А			
Collector power	$T_C = 25^{\circ}C$	P _C	40	W			
dissipation			2.0				
Junction temperature		Tj	150	°C			
Storage temperature	T _{stg}	-55 to +150	°C				





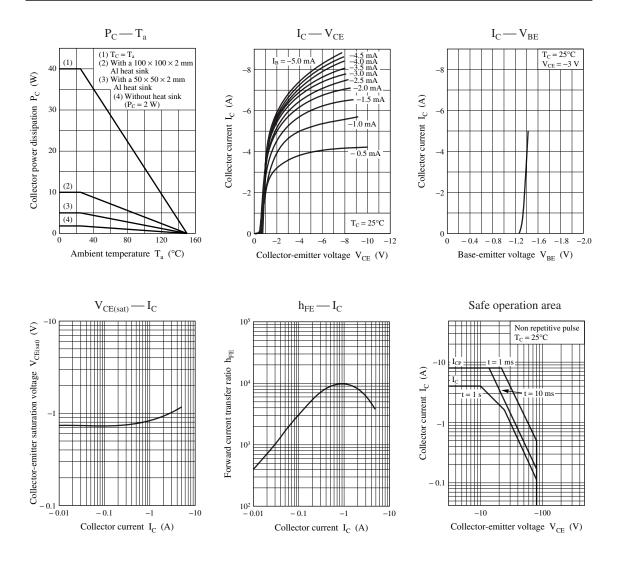
Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-emitter voltage (Base open)	V _{CEO}	$I_{\rm C} = -30 \text{ mA}, I_{\rm B} = 0$	-80			V
Base-emitter voltage	V _{BE}	$V_{CE} = -3 V, I_C = -3 A$			-2.5	V
Collector-base cutoff current (Emitter open)	I _{CBO}	$V_{CB} = -80 \text{ V}, I_E = 0$			-200	μΑ
Collector-emitter cutoff current (Base open)	I _{CEO}	$V_{CE} = -40 \text{ V}, I_B = 0$			-500	μΑ
Emitter-base cutoff current (Collector open)	I _{EBO}	$V_{EB} = -5 V, I_C = 0$			-2	mA
Forward current transfer ratio	h _{FE1}	$V_{CE} = -3 V, I_C = -0.5 A$	1 0 0 0			
	h _{FE2} *	$V_{CE} = -3 V, I_C = -3 A$	1 0 0 0		10 000	
Collector-emitter saturation voltage	V _{CE(sat)1}	$I_{\rm C} = -3$ A, $I_{\rm B} = -12$ mA			-2	V
	V _{CE(sat)2}	$I_{\rm C} = -5 \text{ A}, I_{\rm B} = -20 \text{ mA}$			-4	
Transition frequency	f _T	$V_{CE} = -10 \text{ V}, I_C = -0.5 \text{ A}, f = 1 \text{ MHz}$		20		MHz
Turn-on time	t _{on}	$I_{C} = -3 \text{ A}, I_{B1} = -12 \text{ mA}, I_{B2} = 12 \text{ mA}$		0.3		μs
Storage time	t _{stg}	$V_{CC} = -50 \text{ V}$		2.0		μs
Fall time	t _f			0.5		μs

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors. 2. *: Rank classification

Rank	R	Q	Р
h _{FE2}	1000 to 2500	2000 to 5000	4000 to 10000

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